

30BQ060

Technical Data Data Sheet N0675, Rev. - Green Products

30BQ060 SCHOTTKY RECTIFIER

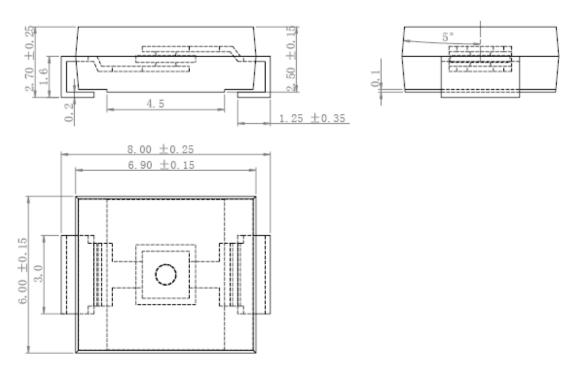
Applications:

- Disk Drives
- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery Charging

Features:

- Small foot print, surface moutable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions (In mm / Inches):



SMC

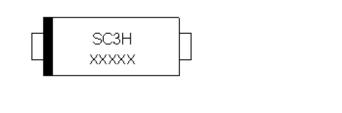
http://www.smc-diodes.com - sales@ smc-diodes.com •



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Marking Diagram:



SC3H = Part Name

30311	- Fait Name		
YY	= Year		
WW	= Week		
L	= Lot Number		

Where XXXXX is YYWWL

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
30BQ060	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	60	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _c =123°C, rectangular wave form	3.0	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	156	А



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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3 A, Pulse, T _J = 25 °C	0.58	V
		@ 6 A, Pulse, T _J = 25 °C	0.76	
	V _{F2}	@ 3 A, Pulse, T _J = 125 °C	0.52	V
		@ 6 A, Pulse, T _J = 125°C	0.66	
Reverse Current *	I _{R1}	$@V_R = Rated V_R$, Pulse,	0.5	mA
		T _J = 25 °C		
	I _{R2}	$@V_R = Rated V_R$, Pulse,	20	mA
		T _J = 125 °C		
Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	180	PF
		f _{SIG} = 1MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	3.0	nH
	_	package body		
Voltage Rate of Change	dv/dt	-	10,000	V/µs

 $\ast\,$ Pulse Width < 300µs, Duty Cycle < 2%

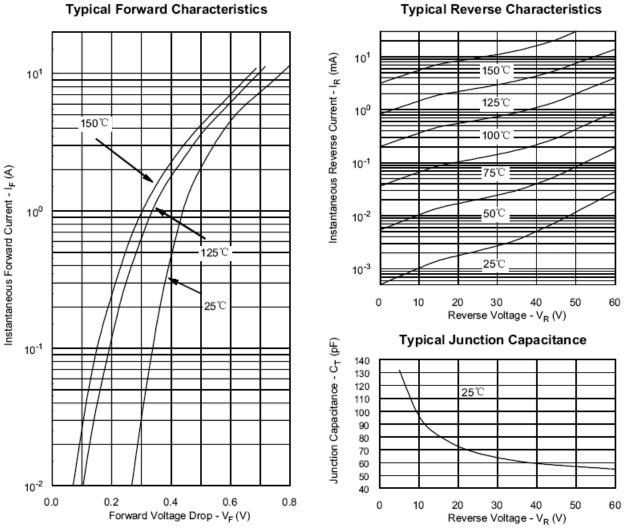
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	$R_{ ext{ heta}JL}$	DC operation	12	°C/W
Typical Thermal Resistance Junction to Case	$R_{ extsf{ heta}JA}$	DC operation	46	°C/W
Approximate Weight	wt	-	0.65	g
Case Style	SMC			

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